

REGULATORY COMPLIANCE

 <p>Lead Free COMPLIANT</p>	 <p>EU RoHS 2011/65 + 2015/863 COMPLIANT</p>	 <p>China RoHS COMPLIANT</p>	 <p>REACH SVHC COMPLIANT</p>	 <p>DRC CONFLICT FREE</p>
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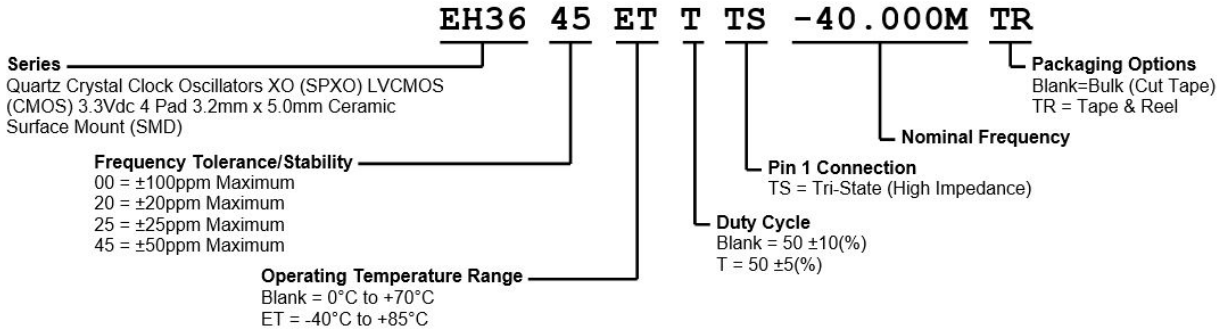
ITEM DESCRIPTION

Quartz Crystal Clock Oscillators XO (SPXO) LVCMOS (CMOS) 3.3Vdc 4 Pad 3.2mm x 5.0mm Ceramic Surface Mount (SMD)

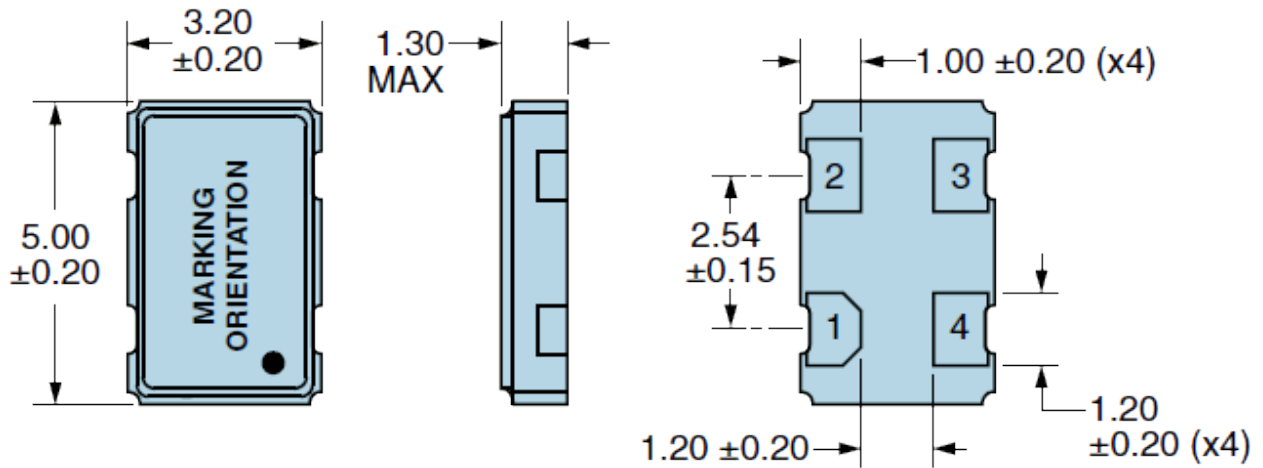
ELECTRICAL SPECIFICATIONS

Nominal Frequency	1MHz to 155.52MHz
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, 1st Year Aging at 25°C, Shock, and Vibration ±100ppm Maximum ±20ppm Maximum ±25ppm Maximum ±50ppm Maximum
Aging at 25°C	±5ppm/year Maximum
Operating Temperature Range	0°C to +70°C -40°C to +85°C
Supply Voltage	3.3Vdc ±10%
Input Current	No Load 35mA Maximum
Output Voltage Logic High (V_{OH})	I _{OH} = -8mA 2.7Vdc Minimum
Output Voltage Logic Low (V_{OL})	I _{OL} = +8mA 0.5Vdc Maximum
Rise/Fall Time	Measured at 20% to 80% of waveform 6nSec Maximum over Nominal Frequency of 1MHz to 70MHz 4nSec Maximum over Nominal Frequency of 70.000001MHz to 155.52MHz
Duty Cycle	Measured at 50% of waveform 50 ±10(%) 50 ±5(%)
Load Drive Capability	30pF Maximum over Nominal Frequency of 1MHz to 70MHz 15pF Maximum over Nominal Frequency of 70.000001MHz to 155.52MHz
Output Logic Type	CMOS
Pin 1 Connection	Tri-State (High Impedance)
Tri-State Input Voltage (V_{IH} and V_{IL})	70% of V _{DD} Minimum to enable output, 20% of V _{DD} Maximum to disable output, No Connect to enable output.
Absolute Clock Jitter	±250pSec Maximum, ±100pSec Typical
One Sigma Clock Period Jitter	±50pSec Maximum, ±40pSec Typical
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

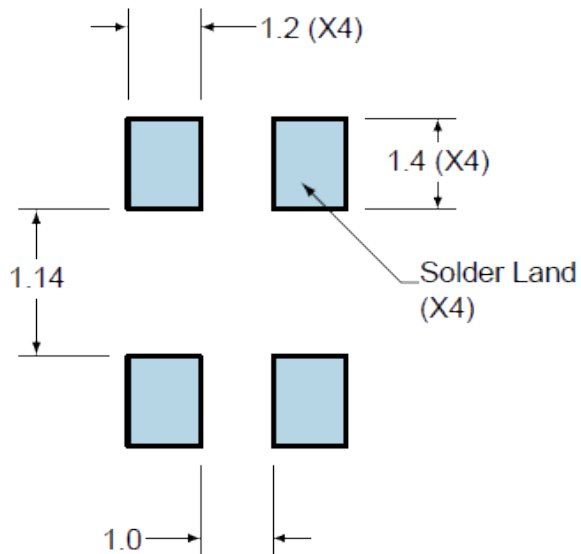
PART NUMBERING GUIDE



MECHANICAL DIMENSIONS



SUGGESTED SOLDER PAD LAYOUT

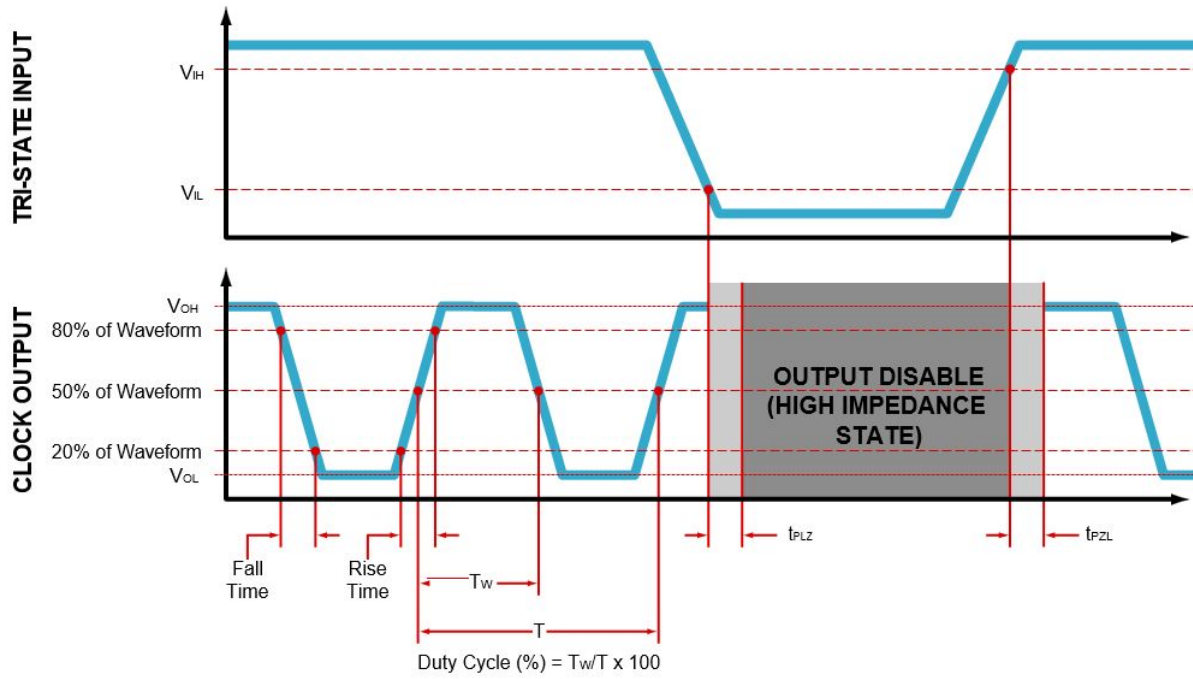


PIN	CONNECTION
1	Tri-State
2	Ground/Case Ground
3	Output
4	Supply Voltage

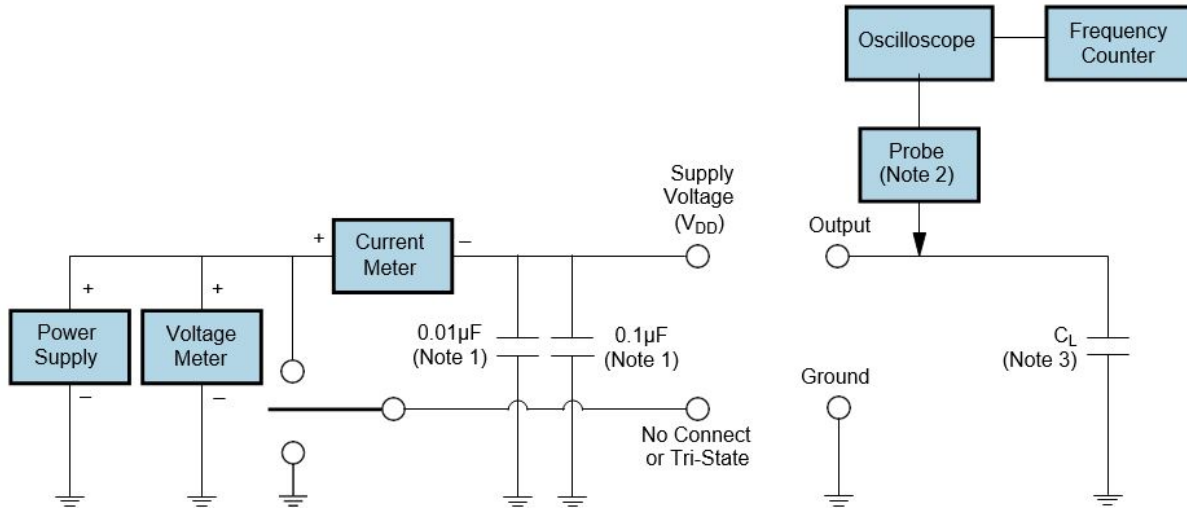
All Tolerances are ± 0.1

All Dimensions in Millimeters

OUTPUT WAVEFORM & TIMING DIAGRAM



TEST CIRCUIT FOR CMOS OUTPUT



Note 1: An external $0.1\mu\text{F}$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu\text{F}$ high frequency ceramic bypass Capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance ($<12\text{pF}$), 10X attenuation factor, high impedance ($>10\text{Mohms}$), and high bandwidth ($>300\text{MHz}$) passive probe is recommended.

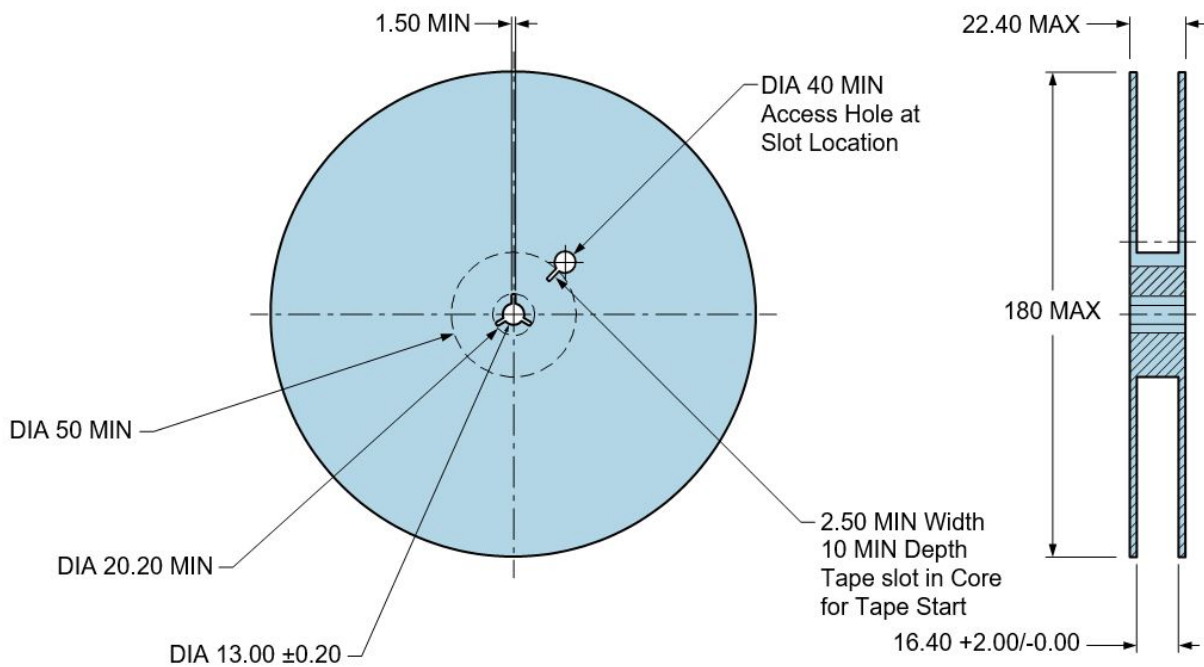
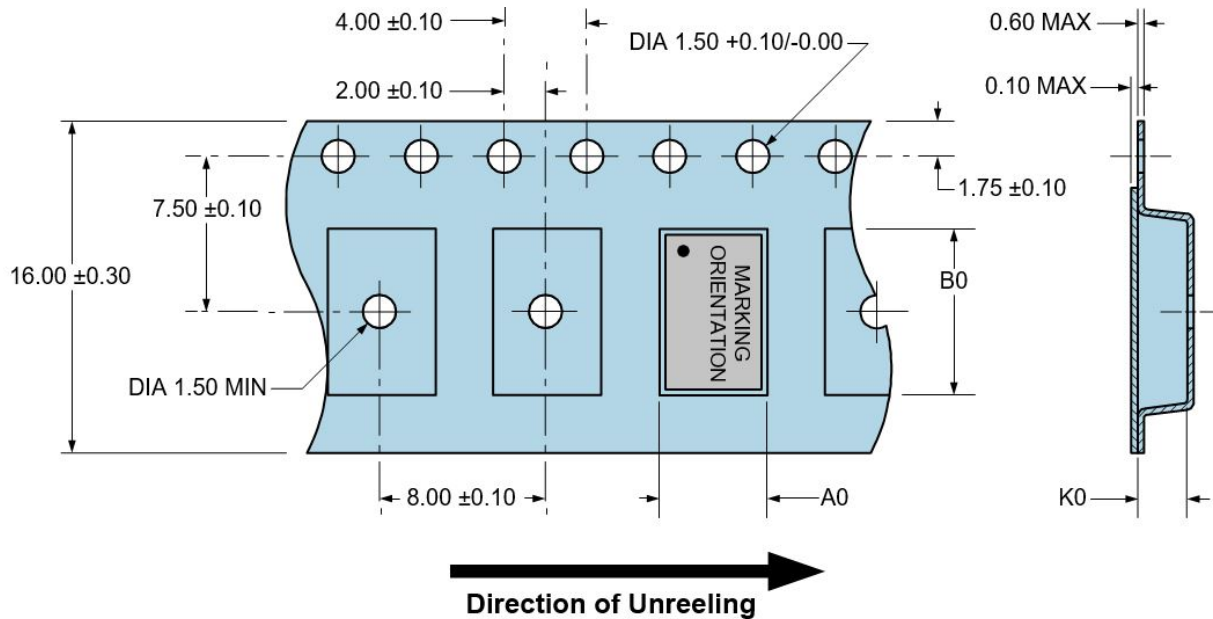
Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance.

TAPE & REEL DIMENSIONS

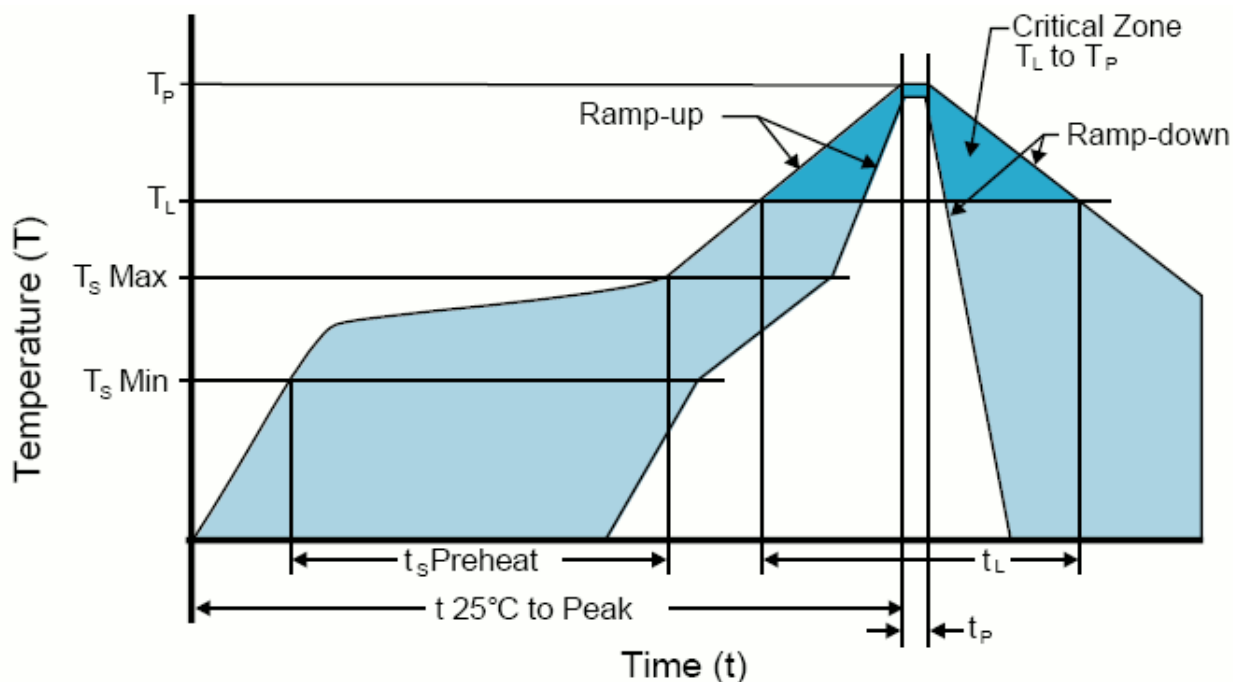
Quantity per Reel: 1,000 Units

All Dimensions in Millimeters

Compliant to EIA-481



RECOMMENDED SOLDER REFLOW METHOD



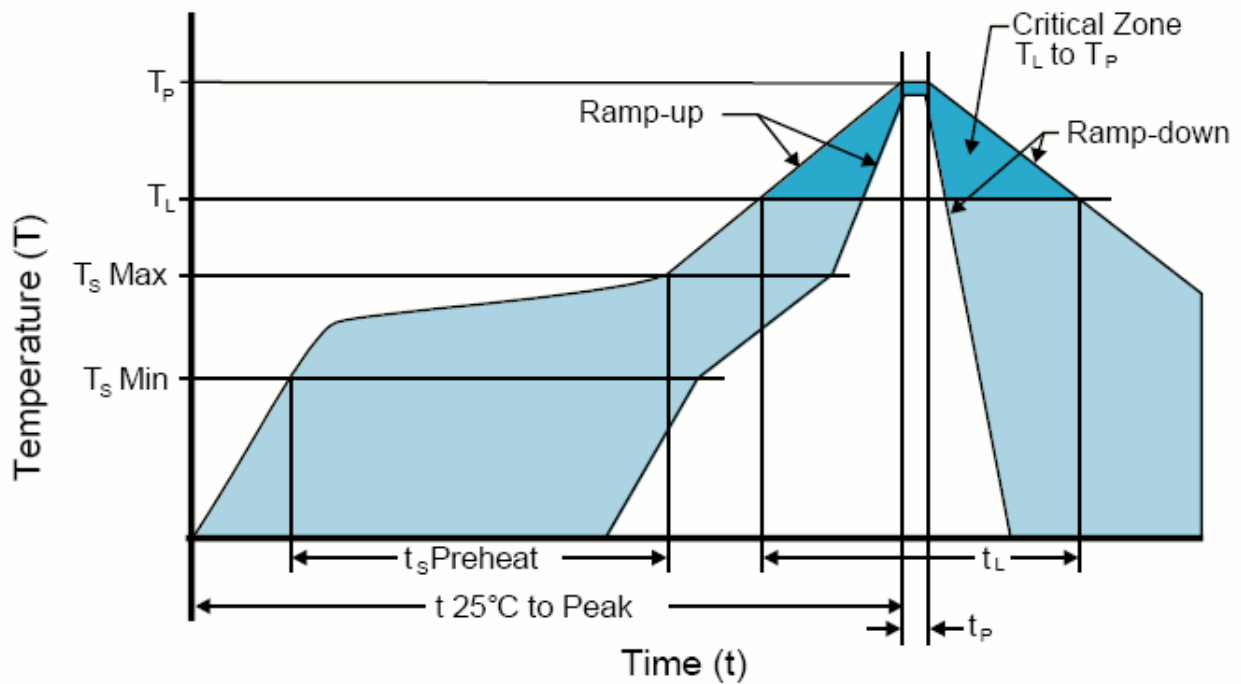
HIGH TEMPERATURE INFRARED/CONVECTION

T_S MAX to T_L (Ramp-up Rate)	3°C/Second Maximum
Preheat	
- Temperature Minimum (T _S MIN)	150°C
- Temperature Typical (T _S TYP)	175°C
- Temperature Maximum(T _S MAX)	200°C
- Time (t _s)	60 - 180 Seconds
Ramp-up Rate (T_L to T_P)	3°C/Second Maximum
Time Maintained Above:	
- Temperature (T _L)	217°C
- Time (t _L)	60 - 150 Seconds
Peak Temperature (T_P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature(T_P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t_p)	20 - 40 Seconds
Ramp-down Rate	6°C/Second Maximum
Time 25°C to Peak Temperature (t)	8 Minutes Maximum
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)

RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION

T_S MAX to T_L (Ramp-up Rate)	5°C/Second Maximum
Preheat	
- Temperature Minimum (T _S MIN)	N/A
- Temperature Typical (T _S TYP)	150°C
- Temperature Maximum(T _S MAX)	N/A
- Time (t _s)	60 - 120 Seconds
Ramp-up Rate (T_L to T_P)	5°C/Second Maximum
Time Maintained Above:	
- Temperature (T _L)	150°C
- Time (t _L)	200 Seconds Maximum
Peak Temperature (T_P)	240°C Maximum
Target Peak Temperature(T_P Target)	240°C Maximum 2 Times/230°C Maximum 1Time
Time within 5°C of actual peak (t_P)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time
Ramp-down Rate	5°C/Second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)

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[SiT8209AI-32-33E-125.000000](#) [SIT8918AA-11-33S-50.000000G](#) [SM4420TEV-40.0M-T1K](#) [F335-24](#) [F335-40](#) [F535L-10](#) [F535L-12](#) [F535L-16](#) [F535L-24](#) [F535L-27](#) [F535L-48](#) [PE7744DW-100.0M](#) [CSX-750FCC14745600T](#) [ASF1-3.686MHZ-N-K-S](#) [XO57CTECNA3M6864](#) [ECS-2100A-147.4](#) [601251](#) [EP16E7E2H26.000MTR](#) [SIT8918AA-11-33S-16.000000G](#) [XO3003](#) [9120AC-2D2-33E212.500000](#) [9102AI-243N25E100.00000](#) [8208AC-82-18E-25.00000](#) [ASDK2-32.768KHZ-LR-T3](#) [8008AI-72-XXE-24.545454E](#) [8004AC-13-33E-133.33000X](#) [AS-4.9152-16-SMD-TR](#) [ASFL1-48.000MHZ-LC-T](#) [SIT8920AM-31-33E-25.0000](#) [DSC1028DI2-019.2000](#) [9121AC-2C3-25E100.00000](#) [9102AI-233N33E100.00000X](#) [9102AI-233N25E200.00000](#) [9102AI-232H25S125.00000](#) [9102AI-133N25E200.00000](#) [9102AC-283N25E200.00000](#) [9001AC-33-33E1-30.000](#) [XLH536125.000JS4I](#) [3921AI-2CF-33NZ125.000000](#) [5730-1SF](#) [PXA000010](#) [XLH535050.000000X](#)